UNISONIC TECHNOLOGIES CO., LTD

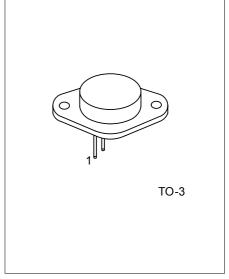
2N2955

PNP SILICON TRANSISTOR

SILICON PNP TRANSISTORS

DESCRIPTION

The UTC 2N2955 is a silicon PNP transistor in TO-3 metal case. It is intended for power switching circuits, series and shunt regulators, output stages and high fidelity amplifiers.

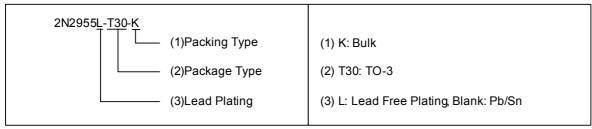


*Pb-free plating product number:2N2955L

ORDERING INFORMATION

Order Number		Doolsono	Pin Assignment			Dooking
Normal	Lead Free Plating	Package	1	2	3	Packing
2N2955-T30-K	2N2955L-T30-K	TO-3	F	В	С	Bulk

Note: 3: Case



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■ **ABSOLUTE MAXIMUM RATINGS** (Ta=25°C ,unless otherwise specified)

PARAMETERS	SYMBOL	RATINGS	UNITS
Collector-Base Voltage		100	V
Collector-Emitter Voltage	V_{CEO}	60	V
Emitter-Base Voltage	V_{EBO}	7	V
Collector-Emitter Voltage	V_{CEV}	70	V
Collector Current	Ic	15	Α
Collector Peak Current(1)	I _{CM}	15	Α
Base Current	I_{B}	7	Α
Base Peak Current(1)	I_{BM}	15	Α
Total Dissipation at Ta=25°C	P_D	115	W
Max. Operating Junction Temperature	TJ	+200	°C
Storage Temperature	T _{STG}	-65 ~ 200	°C

Note Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS (Ta=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
OFF CHARACTERISTICS							
Collector-Emitter Sustaining Voltage	V _{CEO(SUS)}	I _C =200mA, I _B =0V	60			٧	
Collector-Emitter Sustaining Voltage	V _{CER(SUS)}	I_{C} =0.2 A, R_{BE} =100 Ω	70			V	
Collector Cut-off Current	I _{CEO}	$V_{CE}=30V,I_{B}=0$			0.7	mA	
Collector Cut-off Current	I _{CEX}	V_{CE} =100V, $V_{BE(OFF)}$ =1.5V V_{CE} =100V, $V_{BE(OFF)}$ =1.5V, Ta=150°C			1.0 5.0	mA	
Emitter Cut-off Current	I _{EBO}	V _{BE} =7V, I _C =0			5.0	mA	
ON CHARACTERISTICS							
DC Current Gain(Note)	h _{FE}	I _C =4A,V _{CE} =4V, I _C =10A,V _{CE} =4V	20 5		70		
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	I _C =4A, I _B =400mA I _C =10A, I _B =3.3A			1.1 3.0	V	
Base-Emitter On Voltage	$V_{BE(ON)}$	I _C =4A, V _{CE} =4V			1.5	V	
SECOND BREAKDOWN							
Second Breakdown Collector with Base Forward Biased	ls/b	V _{CE} =60V, T=1.0s, Non-repetitive	2.87			Α	
DYNAMIC CHARACTERISTICS							
Current Gain-Bandwidth Product	f_{T}	I _C =0.5A, V _{CE} =10V, f=1MHz	2.5			MHz	
Small-Signal Current Gain	h_FE	I _C =1A, V _{CE} =4V, f=1kHz	15		120		
Small-Signal Current Gain Cut-off Frequency	fh _{FE}	I _C =1A, V _{CE} =4V, f=1kHz	10			kHz	

 $Note (1) : Pulse \ Test: \ PW \quad 300 \mu s, \ Duty \ Cycle \quad 2\%$

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